

L Number	Hits	Search Text	DB	Time stamp
1	306	semiconductor and (complementary adj bipolar adj transistors)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/05 13:59
2	131	(semiconductor and (complementary adj bipolar adj transistors)) and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/05 14:00
3	120	((semiconductor and (complementary adj bipolar adj transistors)) and electrode) and emitter and base and collector	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/05 14:00
4	74	((((semiconductor and (complementary adj bipolar adj transistors)) and electrode) and emitter and base and collector) and ((polycrystal\$4 adj (silicon or si)) or polysilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/05 14:01

L Number	Hits	Search Text	DB	Time stamp
1	1482	(438/207, 309, 313, 318, 213, 205, 322, 323, 203, "348").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/04/05 15:02